imall

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Typical Applications

Cellular Basestations

Cable Modems

• WiMAX

The HMC316MS8 / HMC316MS8E is ideal for:

ROHS V EARTH FRIENDLY

HMC316MS8 / 316MS8E

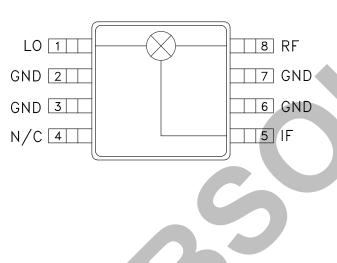
GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz

Features

Conversion Loss: 8 dB LO/RF Isolation: >35 dB Input IP3: +25 dBm Ultra Small Package: <1 mm High Included in the HMC-DK003 Designer's Kit

Functional Diagram

• Fixed Wireless Access Systems



General Description

The HMC316MS8 & HMC316MS8E are miniature double balanced mixers in 8 lead plastic surface mount packages. The passive GaAs schottky diode mixer implements planar on chip balun transformers, and requires no external components. The mixer can be used as an upconverter, downconverter, or modulator. At mid-band the mixer provides 7.5 dB conversion loss and +25 dBm IIP3 with LO drive levels of +19 dBm. The design was optimized for low cost high volume applications where high converter linearity is required.

Electrical Specifications, $T_A = +25^{\circ}$ C, As a Function of LO Drive

Parameter	LO = +15 dBm IF = 100 MHz		LO = +17 dBm IF = 100 MHz			LO = +19 dBm IF = 100 MHz			LO = +19 dBm IF = 500 MHz		Units		
	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	
Frequency Range, RF & LO	1.6 - 3.2		1.6 - 3.2		1.5 - 3.5		3.3 - 3.8		GHz				
Frequency Range, IF		DC - 1.0		DC - 1.0 DC - 1.0 DC -		DC - 1.0	.0 GH						
Conversion Loss		8	11		8	10		7.5	11		9.5		dB
Noise Figure (SSB)		8	11		8	10		7.5	11		9.5		dB
LO to RF Isolation	28	35		32	38		32	42			34		dB
LO to IF Isolation	22	27		24	28		26	30			40		dB
IP3 (Input)	20	25		19	25		19	25			25		dBm
1 dB Gain Compression (Input)	12.5	15.5		14	16		14.5	17			17		dBm

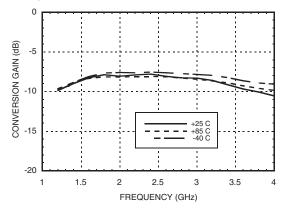
*Unless otherwise noted, all measurements performed as downconverter, IF= 100 MHz.

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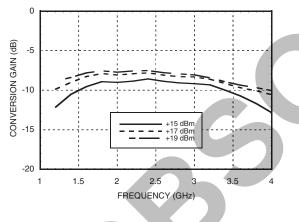




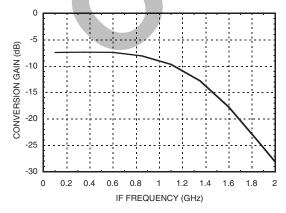
Conversion Gain vs. Temperature @ LO = +17 dBm



Conversion Gain vs. LO Drive

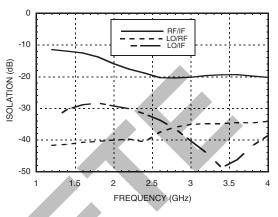


If Bandwidth @ LO = +17 dBm

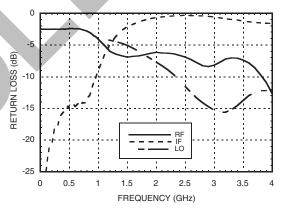


GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz

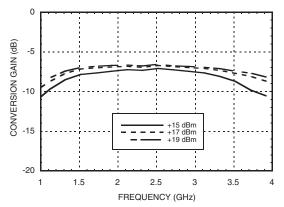
Isolation @ LO = +17 dBm



Return Loss @ LO = +17 dBm



Upconverter Performance vs. LO Drive

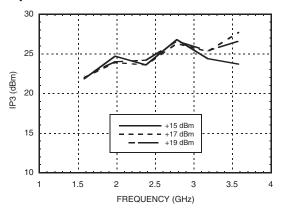


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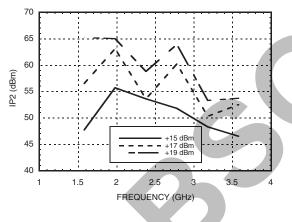




Input IP3 vs. LO Drive*

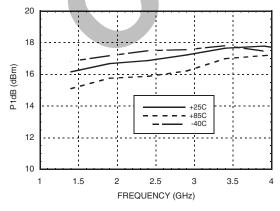


Input IP2 vs. LO Drive*



Input P1dB vs.

Temperature @ LO = +17 dBm



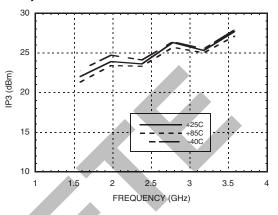
* Two-tone input power = 0 dBm each tone, 1 MHz spacing.

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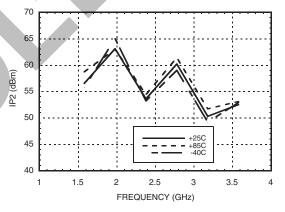
HMC316MS8 / 316MS8E

GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz

Input IP3 vs. Temperature @ LO = +17dBm*



Input IP2 vs. Temperature @ LO = +17 dBm*



MxN Spurious Outputs

	nLO					
mRF	0	1	2	3	4	
0	xx	-8	3.6	1.1	29	
1	10	0	22	44	48	
2	71	72	77	60	85	
3	>110	>110	>110	91	91	
4 >110 >110 >110 >110 >110 >110						
RF = 2.08 GHz @ -10 dBm LO = 1.9 GHz @ +17 dBm						

All values in dBc relative to the IF output power.

9





Absolute Maximum Ratings

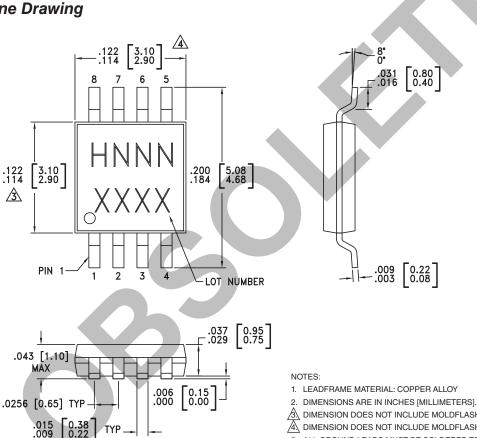
RF / IF Input	+22 dBm
LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
IF DC Current	±18 mA
ESD Sensitivity (HBM)	Class 1A

Outline Drawing

HMC316MS8 / 316MS8E

GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz





- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- A DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- 5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]	
HMC316MS8	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1] H316 XXXX		
HMC316MS8E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H316</u> XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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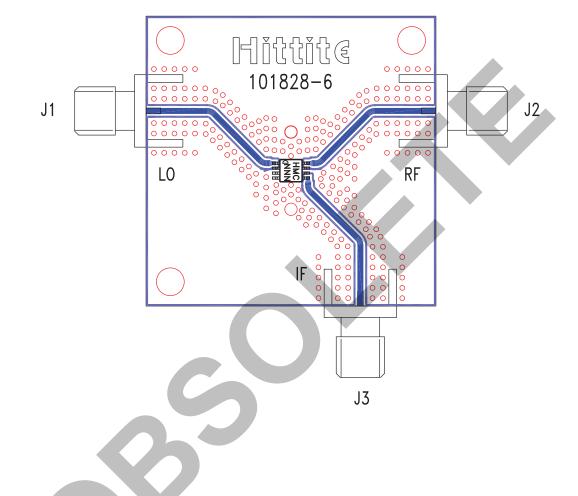


HMC316MS8 / 316MS8E

GaAs MMIC HIGH IP3 DOUBLE-BALANCED MIXER, 1.5 - 3.8 GHz



Evaluation PCB



v02.0505

List of Materials for Evaluation PCB 101830 [1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
U1	HMC316MS8 / HMC316MS8E Mixer
PCB [2]	101828 Eval Board

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown below. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board as shown is available from Hittite upon request.

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HMC316MS8 / 316MS8E

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Notes:

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